TOSHIBA Field-Effect Transistor Silicon P-Channel MOS Type (U-MOSV)

SSM3J129TU

- Power Management Switch Applications
- High-Speed Switching Applications
- 1.5 V drive
- Low ON-resistance $R_{on} = 137m\Omega \text{ (max)} (@V_{GS} = -1.5 \text{ V})$
 - $R_{on} = 88m\Omega (max) (@V_{GS} = -1.8 V)$
 - $R_{on} = 62m\Omega (max) (@V_{GS} = -2.5 V)$
 - $R_{on} = 46m\Omega (max) (@V_{GS} = -4.5 V)$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol		Rating	Unit	
Drain-Source voltage		V _{DSS}		-20	V	
Gate-Source voltage		V _{GSS}		± 8	V	
Drain current	DC	I _D (Note 1)		-4.6	A	
	Pulse	I _{DP} (Note 1)		-9.2		
Drain power dissipation		PD	(Note 2)	500	mW	
			t=10s	1000		
Channel temperature		T _{ch}		150	°C	
Storage temperature range		T _{stg}		–55 to 150	°C	

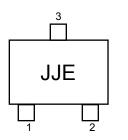
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

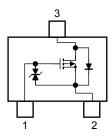
Note 1: The junction temperature should not exceed 150°C during use.

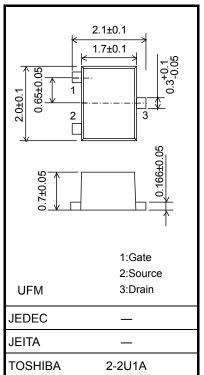
Note 2: Mounted on an FR4 board. (25.4 mm \times 25.4 mm \times 1.6 mm, Cu Pad: 645 mm²)

Marking



Equivalent Circuit (top view)





Weight: 6.6mg (typ.)

Electrical Characteristics (Ta = 25°C)

Chara	cteristic	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain Source brookdown voltage	V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$	-20	_	_	V		
Drain-Source breakdown voltage		V (BR) DSX	$I_D = -1 \text{ mA}, V_{GS} = +8 \text{ V}$	-12	_		_	
Drain cut-off curre	nt	I _{DSS}	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		_	_	-10	μA
Gate leakage curr	ent	I _{GSS}	$V_{GS}=\pm 8~V,~V_{DS}=0~V$		_	_	±1	μA
Gate threshold vo	Itage	V _{th}	$V_{DS} = -3 V$, $I_D = -1 mA$		-0.3	_	-1.0	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = -3 \text{ V}, \text{ I}_{D} = -3.0 \text{ A}$	(Note 3)	6.1	12.2	_	S
Drain-source ON-resistance			$I_D = -3.0 \text{ A}, \text{ V}_{GS} = -4.5 \text{ V}$	(Note 3)	_	37	46	mΩ
		Pro (out)	$I_D = -2.0 \text{ A}, \text{ V}_{GS} = -2.5 \text{ V}$	(Note 3)	_	48	62	
		R _{DS (ON)}	I _D = -1.0 A, V _{GS} = -1.8 V	(Note 3)	_	63	88	
			I _D = -0.3 A, V _{GS} = -1.5 V	(Note 3)	_	78	137	
Input capacitance		C _{iss}			_	640	_	pF
Output capacitance		C _{oss}	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ M}$	_	140	_		
Reverse transfer capacitance		C _{rss}			_	100	_	
Total Gate Charge Gate-Source Charge		Qg	V _{DS} = –10 V, I _D = –4.6 A V _{GS} = –4.5 V		_	8.1	_	nC
		Q _{gs}			_	6.4	_	
Gate-Drain Charge		Q _{gd}			_	1.7	_	
Switching time	Turn-on time	t _{on}	$V_{DD} = -10 \text{ V}, \text{ I}_{D} = -2.0 \text{ A},$			32	_	20
	Turn-off time	t _{off}	V_{GS} = 0 to -2.5 V, R_{G} = 4.7 Ω			102	_	ns
Drain-Source forward voltage		V _{DSF}	$I_D = 4.6 \text{ A}, V_{GS} = 0 \text{ V}$	(Note 3)	_	0.85	1.2	V

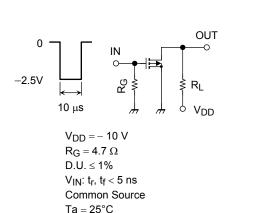
Note3: Pulse test

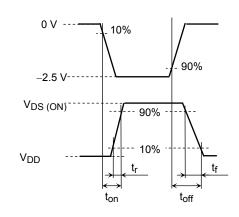
Switching Time Test Circuit

(a) Test Circuit

(b) V_{IN}

(c) VOUT





Notice on Usage

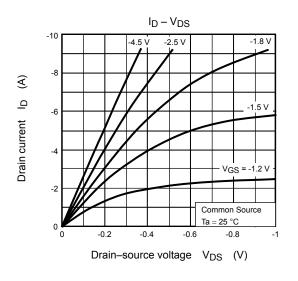
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is $I_D = -1$ mA for this product. For normal switching operation, $V_{GS (on)}$ requires a higher voltage than V_{th} and $V_{GS (off)}$ requires a lower voltage than V_{th} . (The relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on)}$.)

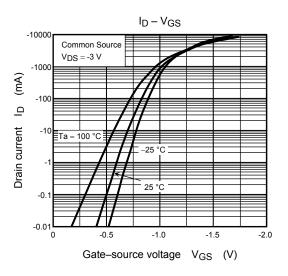
Take this into consideration when using the device.

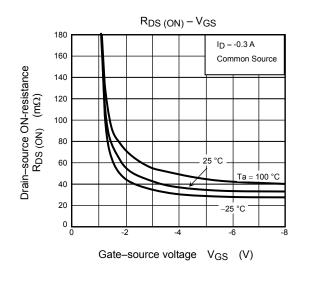
Handling Precaution

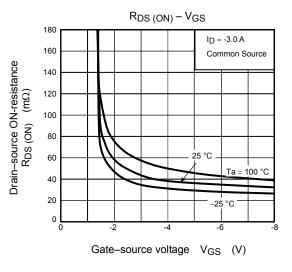
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

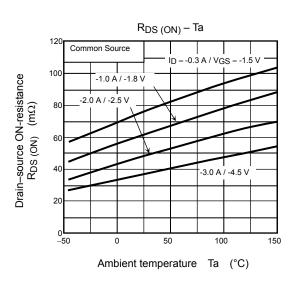
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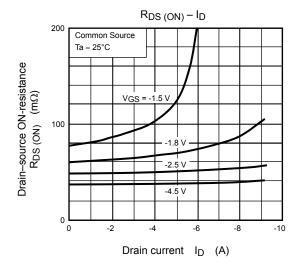






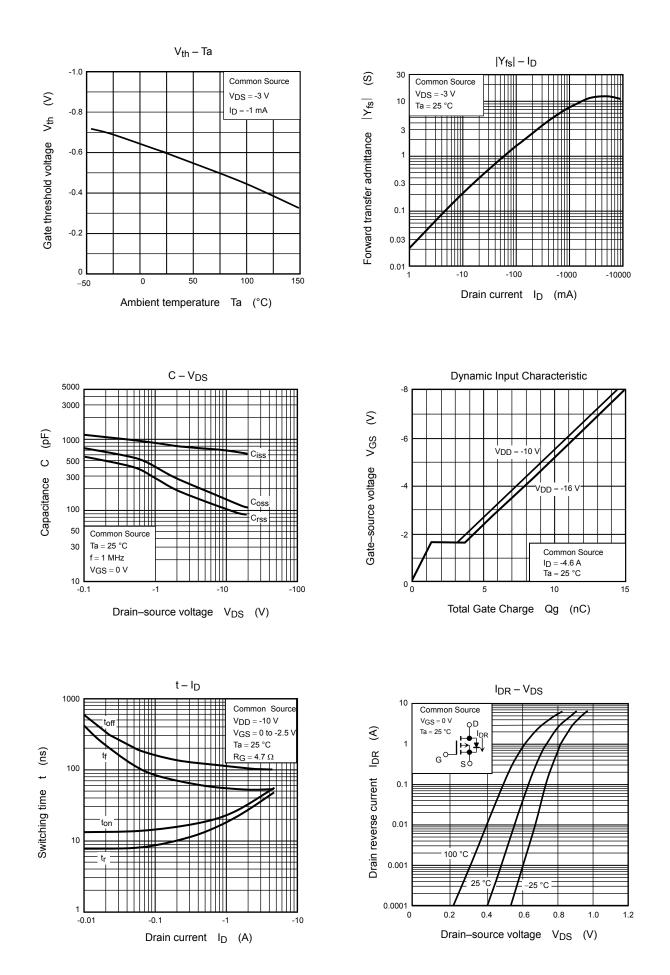




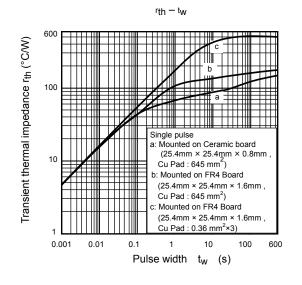


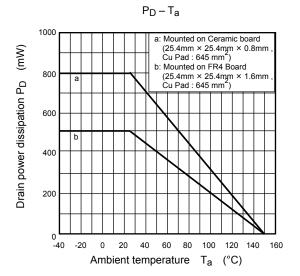
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